

Product data sheet

1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT78 (TO-220AB) plastic package intended for use in applications requiring high bidirectional blocking voltage capability, high current inrush capability and high thermal cycling performance.

2. Features and benefits

- High junction operating temperature capability (T_{i(max)} = 150 °C)
- High thermal cycling performance
- · Planar passivated for voltage ruggedness and reliability
- High voltage capacity
- Very high current surge capability

3. Applications

- DC Motor control
- Power converter
- Lighting and temperature control
- Softstart AC motor control
- AC power control
- Solid State Relay (SSR)

4. Quick reference data

Table 1. Quic	k reference data			
Symbol	Parameter	Conditions	Values	Unit
Absolute m	aximum rating			
V _{RRM}	repetitive peak reverse voltage		1200	V
I _{T(RMS)}	RMS on-state current	half sine wave; $T_{mb} \le 128 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3	31	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 10 \text{ ms}; \frac{\text{Fig. 4}}{25}; \frac{1}{25}$	250	A
		half sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 8.3 \text{ ms}$	275	A
T _j	junction temperature		150	°C

SCR

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>	-	-	35	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	60	mA
V _T	on-state voltage	I _T = 20 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.15	1.5	V
Dynamic	characteristics	·				
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 804 V; T _j = 150 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform;	1000	-	-	V/µs

5. Pinning information

Table 2. P	inning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	А₽К
2	А	anode	204	G sym037
3	G	gate		Symoor
mb	A	mounting base; connected to anode		

6. Ordering information

Table 3. Ordering inform	nation					
Type number	Package					
	Name	Description	Version			
BT152-1200T	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78			

7. Marking

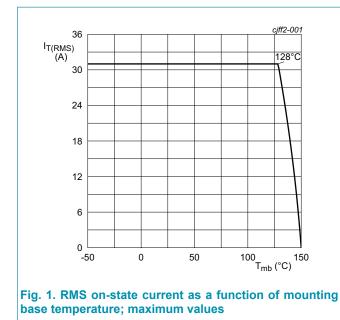
Table 4. Marking codes							
	Type number	Marking codes					
	BT152-1200T	BT152-1200T					

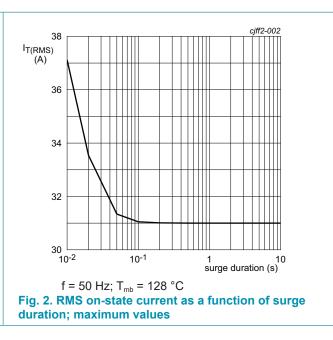
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

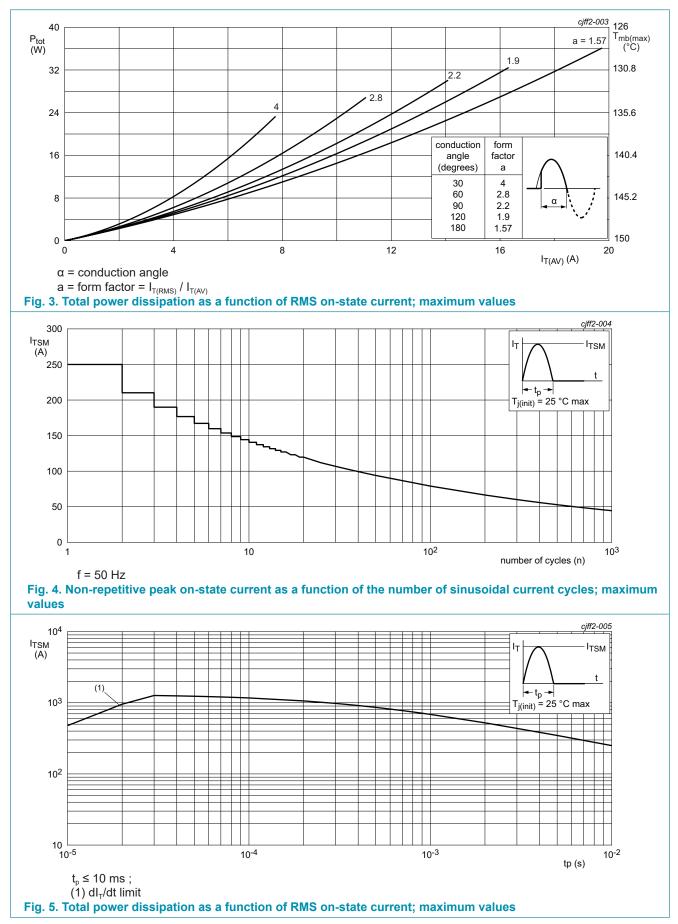
Symbol	Parameter	Conditions	Values	Unit
V _{drm}	repetitive peak off-state voltage		1200	V
V _{RRM}	repetitive peak reverse voltage		1200	V
I _{T(AV)}	average on-state current	half sine wave; $T_{mb} \le 128 \text{ °C}$;	20	A
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 128 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	31	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; Fig. 4; Fig. 5	250	A
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms	275	A
l ² t	l ² t for fusing	t _p = 10ms; sine wave	312.5	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 60mA	150	A/µs
I _{GM}	peak gate current		5	A
V_{GM}	peak gate voltage		5	V
P _{GM}	peak gate power		20	W
P _{G(AV)}	average gate power	over any 20 ms period	0.5	W
T _{stg}	storage temperature		-40 to 150	°C
Tj	junction temperature		150	°C





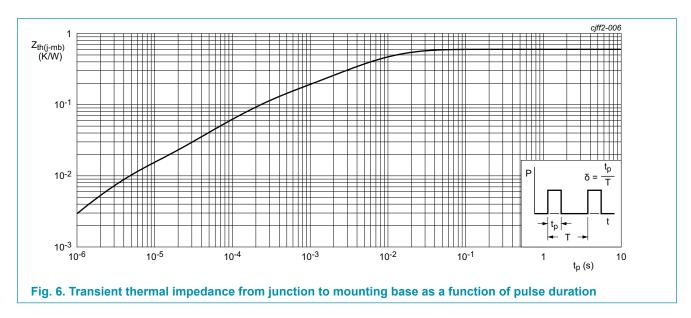
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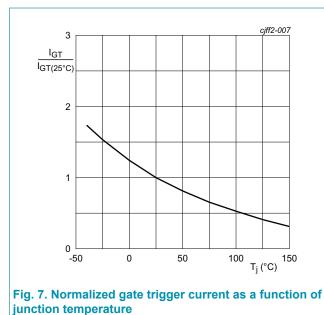
9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<u>Fig. 6</u>	-	-	0.6	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W



10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	racteristics			.,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	Indx	Unit
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _i = 25 °C; <u>Fig. 7</u>	-	-	35	mA
I _L	latching current	$V_{\rm D}$ = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 8	-	-	80	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	 -	-	60	mA
V _T	on-state voltage	I _T = 20 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.15	1.5	V
V _{gt}	gate trigger voltage	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ Fig. 11	-	0.7	1	V
		V _D = 1200 V; I _T = 0.1 A; T _j = 150 °C; Fig. 11	0.25	0.4	-	V
I _D	off-state current	V _D = 1200 V; T _j = 150 °C	-	-	2	mA
I _R	reverse current	V _D = 1200 V; T _j = 150 °C	-	-	2	mA
Dynamic o	haracteristics	· · · · · · · · · · · · · · · · · · ·				_
dV_D/dt	rate of rise of off-state voltage	V_{DM} = 804 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform	1000	-	-	V/µs
t _{gt}	gate-controlled turn-on time	I_{TM} = 20 A; V _D = 800 V; I _G = 100 mA; (dI _G /dt) _M = 5 A/µs; T _j = 25 °C		2	-	μs
t _q	commutated turn-off time			70	-	μs



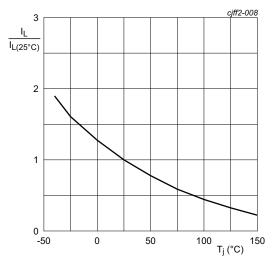
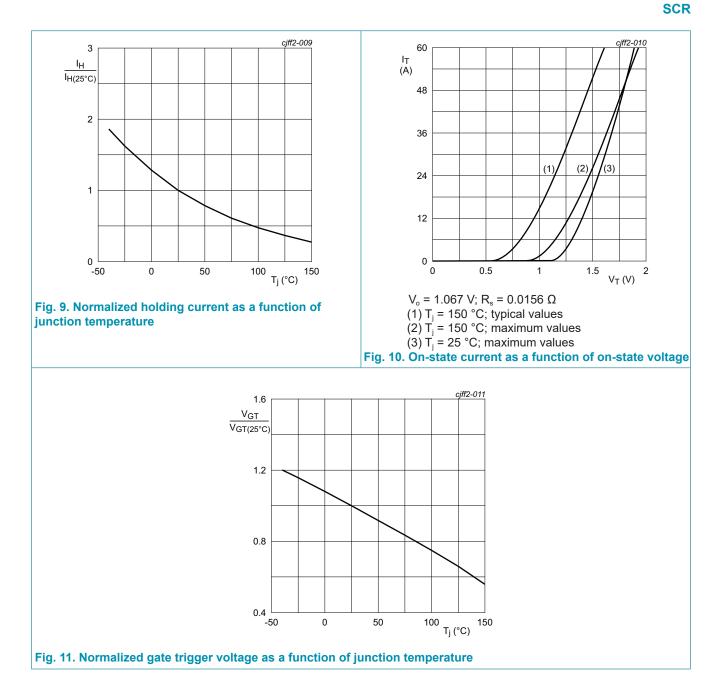


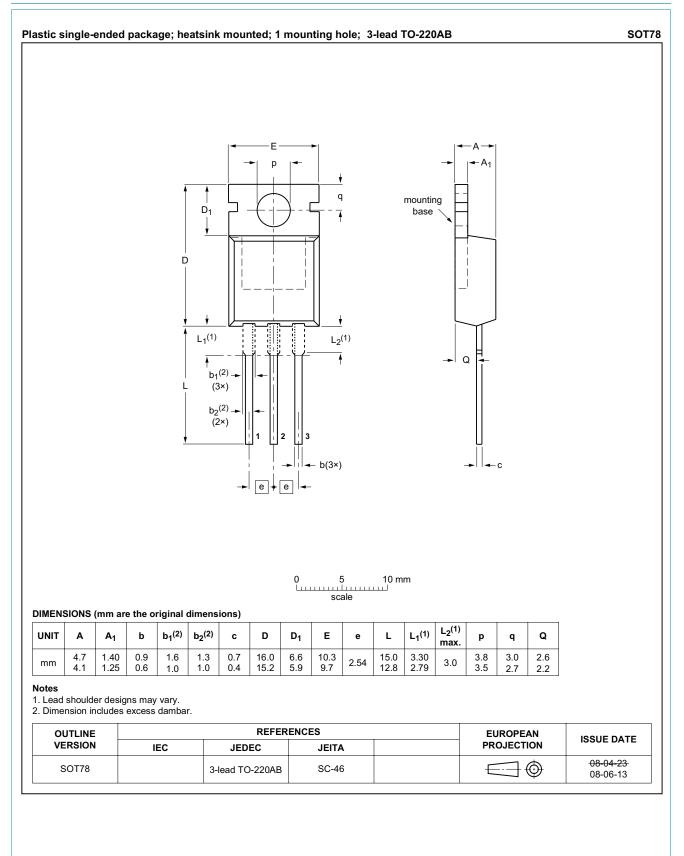
Fig. 8. Normalized latching current as a function of junction temperature

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BT152-1200T



11. Package outline



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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